

# Power transistor (60V, 2A)

## 2SC5880

### ●Features

- 1) High speed switching.  
( $t_f$  : Typ. : 35ns at  $I_c = 2A$ )
- 2) Low saturation voltage, typically  
(Typ. : 200mV at  $I_c = 1.0A, I_B = 100mA$ )
- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SA2093

### ●Applications

Low frequency amplifier  
High speed switching

### ●Structure

NPN Silicon epitaxial planar transistor

### ●Packaging specifications

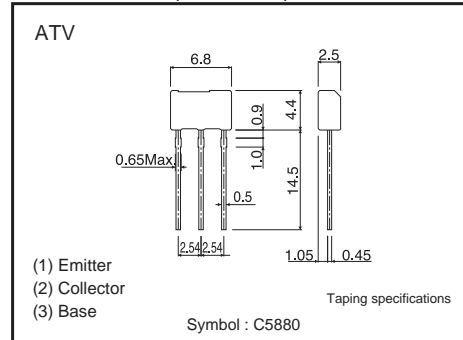
Type	Package	Taping
	Code	TV2
	Basic ordering unit (pieces)	2500
2SC5880		○

### ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Collector-base voltage	$V_{CBO}$	60	V	
Collector-emitter voltage	$V_{CEO}$	60	V	
Emitter-base voltage	$V_{EBO}$	6	V	
Collector current	DC	$I_c$	2	A
	Pulsed	$I_{CP}$	4	A *
Power dissipation	$P_C$	1.0	W	
Junction temperature	$t_j$	150	°C	
Range of storage temperature	$t_{stg}$	-55 to 150	°C	

\*Pw=10ms

### ●Dimensions (Unit : mm)



●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Collector-emitter breakdown voltage	$BV_{CEO}$	60	–	–	V	$I_C=1mA$
Collector-base breakdown voltage	$BV_{CBO}$	60	–	–	V	$I_C=100\mu A$
Emitter-base breakdown voltage	$BV_{EBO}$	6	–	–	V	$I_E=100\mu A$
Collector cut-off current	$I_{CBO}$	–	–	1.0	$\mu A$	$V_{CB}=40V$
Emitter cut-off current	$I_{EBO}$	–	–	1.0	$\mu A$	$V_{EB}=4V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	–	200	500	mV	$I_C=1.0A$ $I_B=0.1A$
DC current gain	$h_{FE}$	120	–	390	–	$V_{CE}=2V$ $I_C=100mA$
Transition frequency	$f_T$	–	200	–	MHz	$V_{CE}=10V$ $I_E=-100mA$ $f=10MHz$
Corrector output capacitance	$C_{ob}$	–	10	–	pF	$V_{CB}=10V$ $I_E=0mA$ $f=1MHz$
Turn-on time	$t_{on}$	–	50	–	ns	$I_C=2A$ $I_{B1}=200mA$
Storage time	$t_{stg}$	–	120	–	ns	$I_{B2}=-200mA$
Fall time	$t_f$	–	35	–	ns	$V_{CC}\approx 25V$

\*Non repetitive pulse

●hFE RANK

Q	R
120–270	180–390

●Electrical characteristic curves

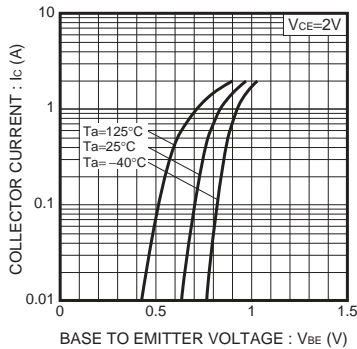


Fig.1 Grounded Emitter Propagation Characteristics

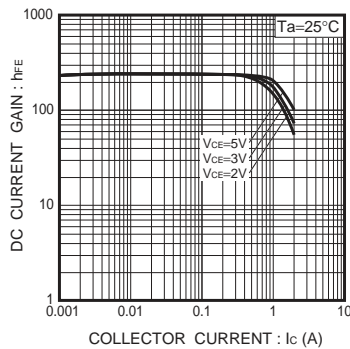


Fig.2 DC Current Gain vs. Collector Current (I)

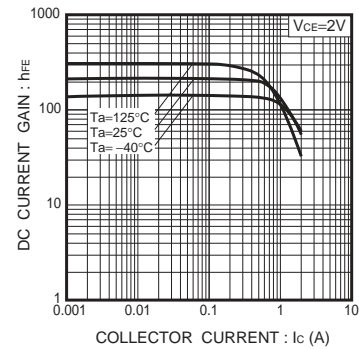


Fig.3 DC Current Gain vs. Collector Current (II)

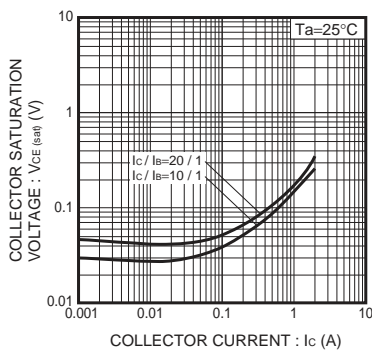


Fig.4 Collector-Emitter Saturation Voltage vs. Collector Current (I)

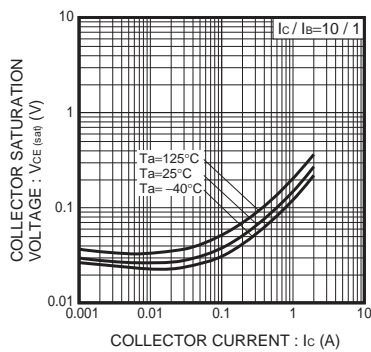


Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (II)

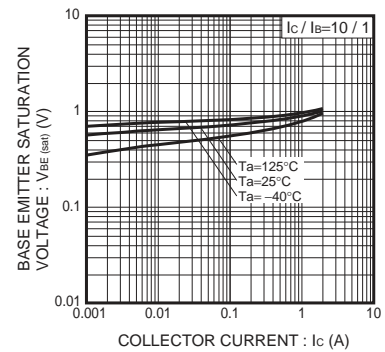


Fig.6 Base-Emitter Saturation Voltage vs. Collector Current

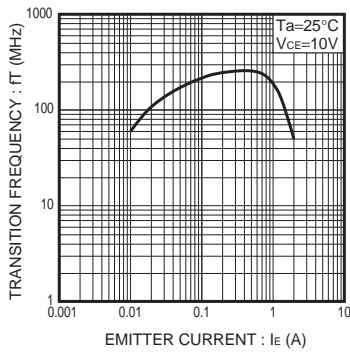


Fig.7 Transition Frequency

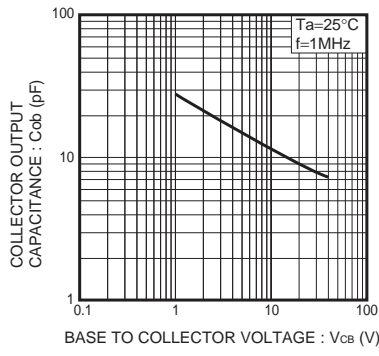


Fig.8 Collector Output Capacitance

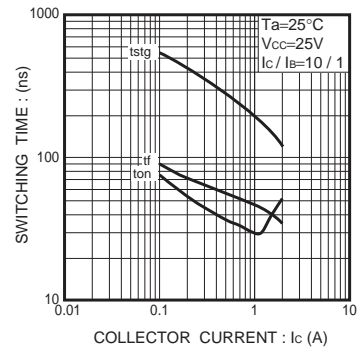
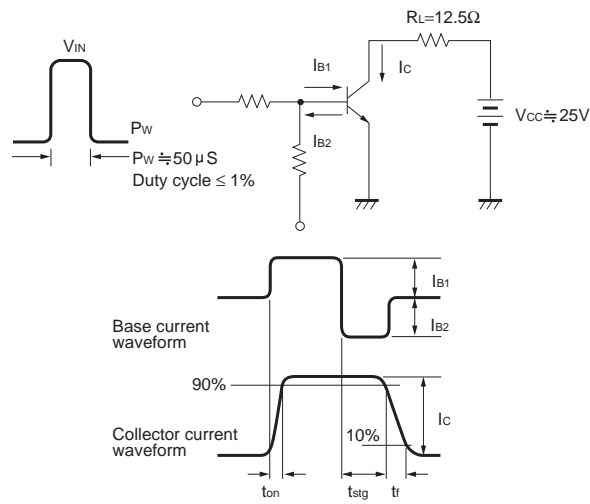


Fig.9 Switching Time

●Switching characteristics measurement circuits



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